

2SJ0582

Silicon P-channel power MOSFET

■ Features

- Avalanche energy capability guaranteed
- High-speed switching
- No secondary breakdown

■ Applications

- Non-contact relay
- Solenoid drive
- Motor drive
- Control equipment
- Switching mode regulator

■ Package

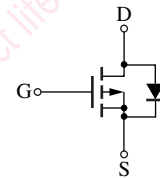
- Code
U-G2
- Pin Name
1: Gate
2: Drain
3: Source

■ Marking Symbol: J0582

■ Internal Connection

■ Absolute Maximum Ratings $T_C = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Drain-source surrender voltage	V_{DSS}	-200	V
Gate-source surrender voltage	V_{GSS}	± 20	V
Drain current	I_D	± 2	A
Peak drain current	I_{DP}	± 4	A
Avalanche energy capability *	EAS	10	mJ
Power dissipation	P_D	10	W
		$T_a = 25^\circ\text{C}$	
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

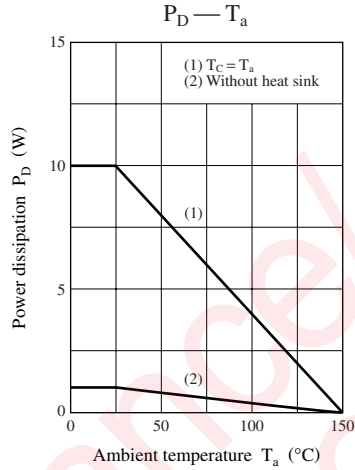
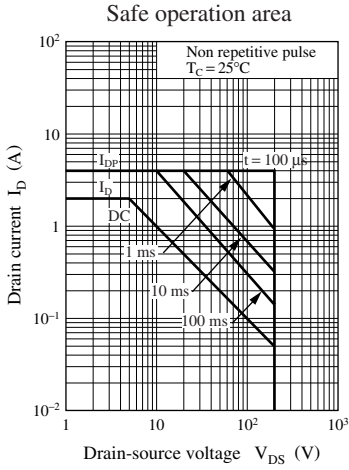


Note) *: $L = 5\text{ mH}$, $I_L = 2\text{ A}$, 1 pulse

■ Electrical Characteristics $T_C = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-source cutoff current	I_{DSS}	$V_{DS} = -160\text{ V}$, $V_{GS} = 0$			-10	μA
Gate-source cutoff current	I_{GSS}	$V_{GS} = \pm 20\text{ V}$, $V_{DS} = 0$			± 10	μA
Drain-source surrender voltage	V_{DSS}	$I_D = -1\text{ mA}$, $V_{GS} = 0$	-200			V
Gate threshold voltage	V_{th}	$V_{DS} = -25\text{ V}$, $I_D = -1\text{ mA}$	-2.0		-4.0	V
Drain-source ON resistance	$R_{DS(on)}$	$V_{GS} = -10\text{ V}$, $I_D = -1.0\text{ A}$		1.5	2.0	Ω
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -25\text{ V}$, $I_D = -1.0\text{ A}$	1.0	1.7		S
Diode forward voltage	V_{DF}	$I_{DR} = -2.0\text{ A}$, $V_{GS} = 0$			1.4	V
Short-circuit forward transfer capacitance (Common source)	C_{iss}	$V_{DS} = -20\text{ V}$, $V_{GS} = 0$, $f = 1\text{ MHz}$		400		pF
Short-circuit output capacitance (Common source)	C_{oss}			55		pF
Reverse transfer capacitance (Common source)	C_{rss}			25		pF
Turn-on delay time	$t_{d(on)}$	$V_{DD} = 100\text{ V}$, $I_D = -1.0\text{ A}$, $R_L = 100\ \Omega$ $V_{GS} = -10\text{ V}$		12		ns
Rise time	t_r			15		ns
Turn-off delay time	$t_{d(off)}$			50		ns
Fall time	t_f			25		ns
Thermal resistance (ch-c)	$R_{th(ch-c)}$					12.5
Thermal resistance (ch-a)	$R_{th(ch-a)}$				125	$^\circ\text{C/W}$

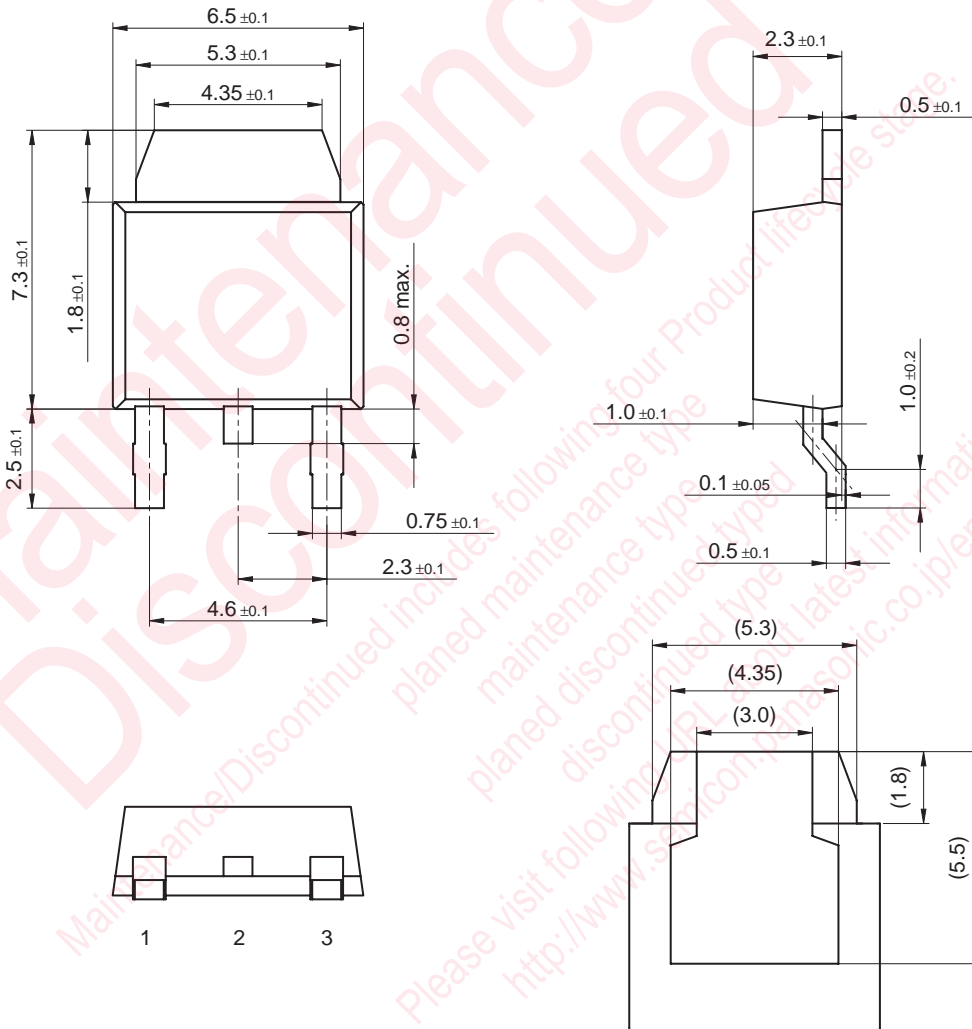
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.



Maintenance/Discontinued includes following four Product lifecycle stage.
 planned maintenance type
 maintenance type
 planned discontinued type
 discontinued type
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U-G2

Unit: mm



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